



### **40V N-Channel Enhancement Mode MOSFET**

Voltage

40 V

Current

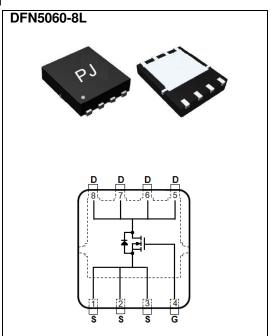
50A

#### **Features**

- $R_{DS(ON)}$ ,  $V_{GS}$ @10V,  $I_{D}$ @20A<11m $\Omega$
- $R_{DS(ON)}$ ,  $V_{GS}$ @4.5V,  $I_{D}$ @10A<15m $\Omega$
- High switching speed
- Improved dv/dt capability
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

#### **Mechanical Data**

- Case: DFN5060-8L Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0028 ounces, 0.08 grams



## **Maximum Ratings and Thermal Characteristics** (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		$V_{DS}$	40	_ v	
Gate-Source Voltage		$V_{GS}$	<u>+</u> 20		
Continuous Drain Current	T <sub>C</sub> =25°C	I <sub>D</sub>	50	A	
	T <sub>C</sub> =100°C		31.5		
Pulsed Drain Current(Note 1)	T <sub>C</sub> =25°C	I <sub>DM</sub>	120		
Power Dissipation	T <sub>C</sub> =25°C	Po	54	W	
	T <sub>C</sub> =100°C		21.6		
Continuous Drain Current	T <sub>A</sub> =25°C	I <sub>D</sub>	9.6	Α	
	T <sub>A</sub> =70°C		7.6	Α	
Power Dissipation	T <sub>A</sub> =25°C	Po	2.0	10/	
	T <sub>A</sub> =70°C		1.3	W	
Single Pulse Avalanche Energy <sup>(Note 6)</sup>		E <sub>AS</sub>	62	mJ	
Operating Junction and Storage Temperature Range		$T_{J}$ , $T_{STG}$	-55~150	°C	
Typical Thermal Resistance <sup>(Note 4,5)</sup>	Junction to Case	$R_{ heta JC}$	2.3	°C/W	
	Junction to Ambient	$R_{\theta JA}$	62.5		

• Limited only By Maximum Junction Temperature





# **Electrical Characteristics** (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	$V_{GS}=0V,I_D=250uA$	40	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=250$ uA	1	1.7	2.5	
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	$V_{GS}=10V,I_{D}=20A$	-	9	11	mΩ
		$V_{GS}=4.5V, I_{D}=10A$	-	11.5	15	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS}$ =40V, $V_{GS}$ =0V	-	-	1	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	$V_{GS}=\underline{+}20V, V_{DS}=0V$	-	-	<u>+</u> 100	nA
Dynamic (Note 7)						
Total Gate Charge	$Q_g$	V <sub>DS</sub> =20V, I <sub>D</sub> =10A, V <sub>GS</sub> =4.5V <sup>(Note 2,3)</sup>	-	10	-	nC
Gate-Source Charge	$Q_gs$		-	3.5	-	
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> =4.3 V	-	3.6	-	
Input Capacitance	Ciss	V 20V V 0V	-	1040	-	pF
Output Capacitance	Coss	V <sub>DS</sub> =20V, V <sub>GS</sub> =0V, f=1.0MHZ	-	117	-	
Reverse Transfer Capacitance	Crss	I=1.UIVIIIZ	-	84	-	
Turn-On Delay Time	td <sub>(on)</sub>		-	9.4	-	ns
Turn-On Rise Time	t <sub>r</sub>	V <sub>DS</sub> =20V,I <sub>D</sub> =1A,	-	19	-	
Turn-Off Delay Time	td <sub>(off)</sub>	$V_{GS}=10V, R_G=6\Omega$ (Note 2,3)	-	66	-	
Turn-Off Fall Time	t <sub>f</sub>		-	67	-	
Drain-Source Diode						
Maximum Continuous Drain-Source	ı		-	-	50	Α
Diode Forward Current	I <sub>S</sub>					
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> =1A,V <sub>GS</sub> =0V	-	0.7	1	V

#### NOTES:

- 1. Pulse width<300us, Duty cycle<2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature  $T_{J(MAX)}=150$ °C. Ratings are based on low frequency and duty cycles to keep initial  $T_J=25$ °C.
- 4. The maximum current rating is package limited.
- 5. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper.
- 6. The test condition is L=0.1mH,  $I_{AS}$ =35A,  $V_{DD}$ =25V,  $V_{GS}$ =10V, Starting  $T_{J}$ =25°C.
- 7. Guaranteed by design, not subject to production testing.





#### TYPICAL CHARACTERISTIC CURVES

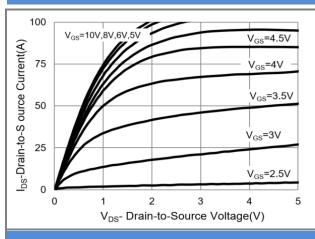
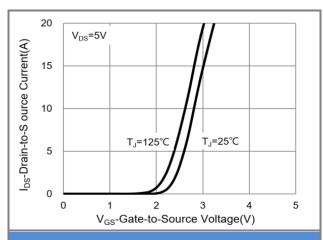


Fig.1 On-Region Characteristics



**Fig.2 Transfer Characteristics** 

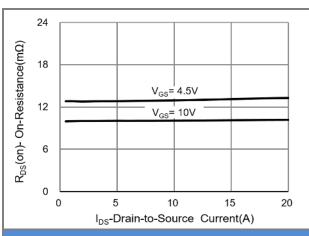


Fig.3 On-Resistance vs. Drain Current

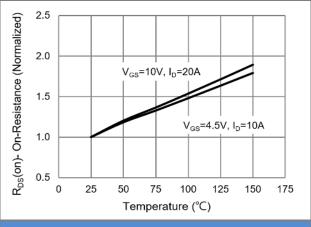


Fig.4 On-Resistance vs. Junction temperature

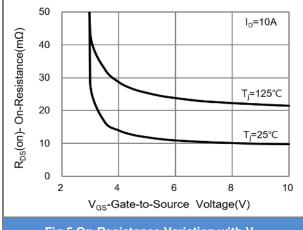
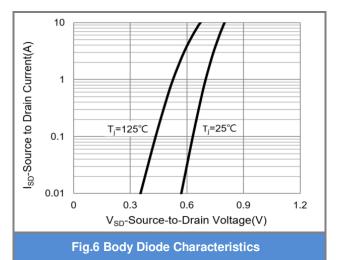


Fig.5 On-Resistance Variation with  $V_{\text{GS}}$ 



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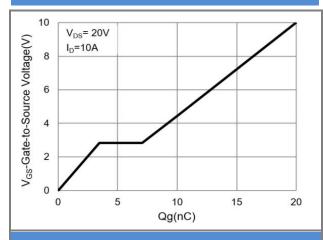


Fig.7 Gate-Charge Characteristics

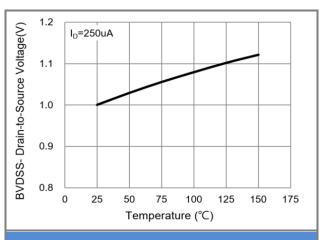


Fig.8 Breakdown Voltage Variation vs. Temperature

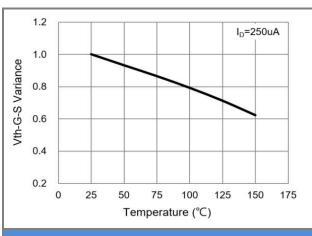


Fig.9 Threshold Voltage Variation with Temperature

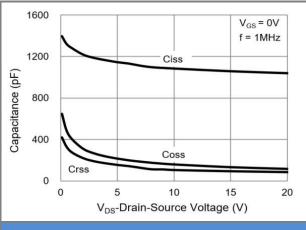


Fig.10 Capacitance vs. Drain-Source Voltage

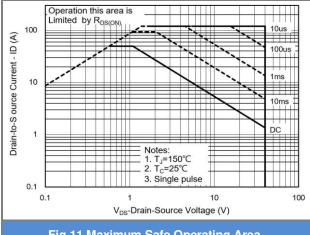


Fig.11 Maximum Safe Operating Area

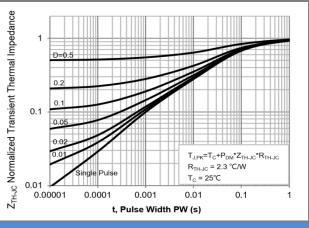


Fig.12 Normalized Transient Thermal Impedance

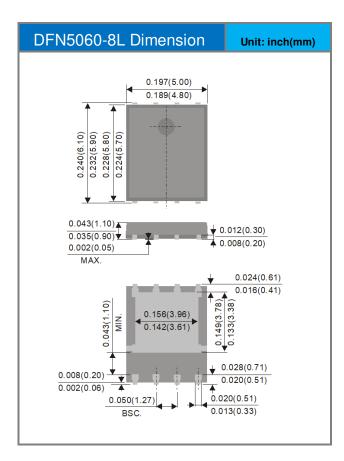


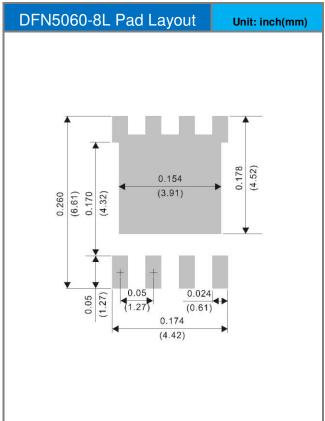


### **Part No Packing Code Version**

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJQ5448_R2_00001	DFN5060-8L	3000pcs / 13" reel	Q5448	Halogen free

### **Packaging Information & Mounting Pad Layout**









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